

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX138FT

Low Voltage 3-to-8 Line Decoder with 3.6 V Tolerant Inputs and Outputs

The TC74VCX138FT is a high performance CMOS 3-to-8 DECODER. Designed for use in 1.8, 2.5 or 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

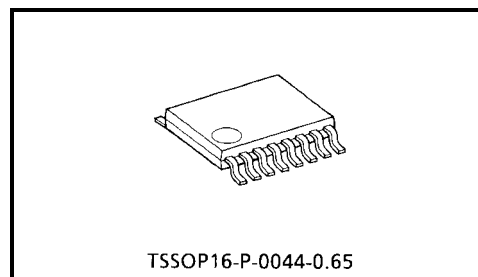
It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs ($\bar{Y}0 \sim \bar{Y}7$) will go low.

When enable input G1 is held low or either $\bar{G}2A$ or $\bar{G}2B$ is held high, decoding function is inhibited and all outputs go high.

G1, $\bar{G}2A$, and $\bar{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.06 g (typ.)

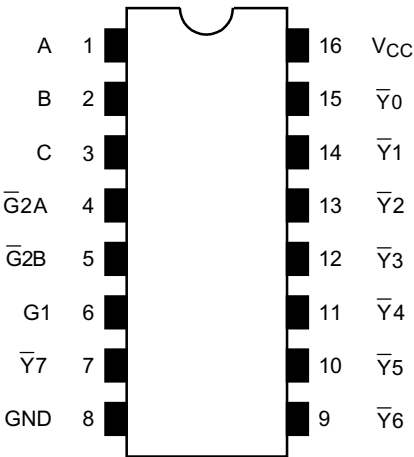
Features

- Low voltage operation: $V_{CC} = 1.8 \sim 3.6$ V
- High speed operation: $t_{pd} = 3.5$ ns (max) ($V_{CC} = 3.0 \sim 3.6$ V)
 $t_{pd} = 4.1$ ns (max) ($V_{CC} = 2.3 \sim 2.7$ V)
 $t_{pd} = 8.2$ ns (max) ($V_{CC} = 1.8$ V)
- 3.6 V tolerant inputs and outputs.
- Output current: $I_{OH}/I_{OL} = \pm 24$ mA (min) ($V_{CC} = 3.0$ V)
 $I_{OH}/I_{OL} = \pm 18$ mA (min) ($V_{CC} = 2.3$ V)
 $I_{OH}/I_{OL} = \pm 6$ mA (min) ($V_{CC} = 1.8$ V)
- Latch-up performance: ± 300 mA
- ESD performance: Human body model $> \pm 2000$ V
Machine model $> \pm 200$ V
- Package: TSSOP (thin shrink small outline package)
- Power down protection is provided on all inputs and outputs.

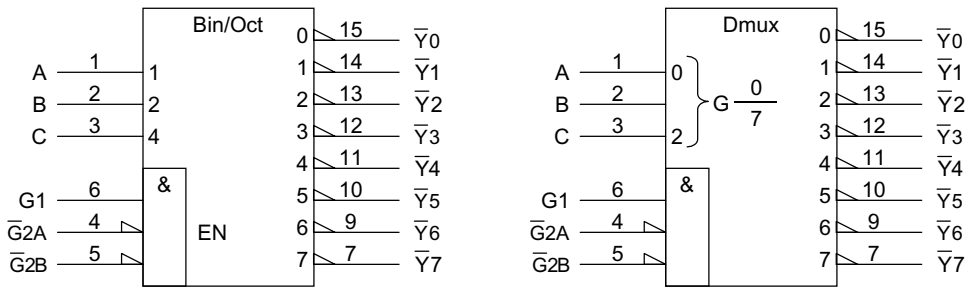
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Pin Assignment (top view)



IEC Logic Symbol

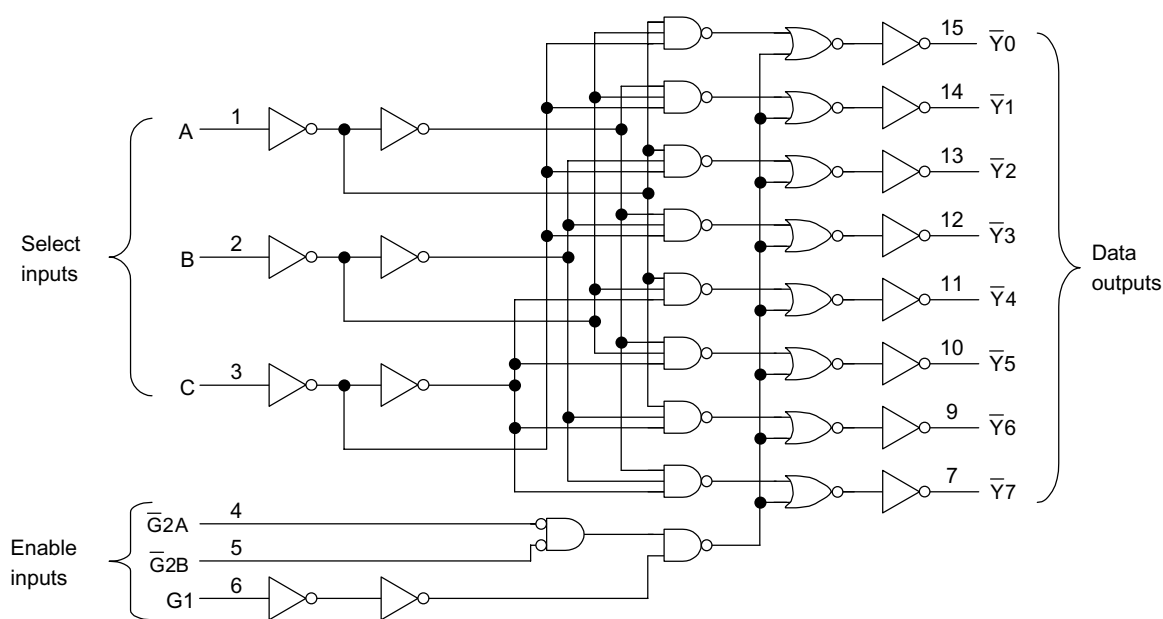


Truth Table

Inputs						Outputs								Selected Output
Enable			Select			$\overline{Y}0$	$\overline{Y}1$	$\overline{Y}2$	$\overline{Y}3$	$\overline{Y}4$	$\overline{Y}5$	$\overline{Y}6$	$\overline{Y}7$	
G1	$\overline{G}2A$	$\overline{G}2B$	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	None
X	H	X	X	X	X	H	H	H	H	H	H	H	H	None
X	X	H	X	X	X	H	H	H	H	H	H	H	H	None
H	L	L	L	L	L	L	H	H	H	H	H	H	H	$\overline{Y}0$
H	L	L	L	L	H	H	L	H	H	H	H	H	H	$\overline{Y}1$
H	L	L	L	H	L	H	H	L	H	H	H	H	H	$\overline{Y}2$
H	L	L	L	H	H	H	H	H	L	H	H	H	H	$\overline{Y}3$
H	L	L	H	L	L	H	H	H	H	L	H	H	H	$\overline{Y}4$
H	L	L	H	L	H	H	H	H	H	H	L	H	H	$\overline{Y}5$
H	L	L	H	H	L	H	H	H	H	H	H	L	H	$\overline{Y}6$
H	L	L	H	H	H	H	H	H	H	H	H	H	L	$\overline{Y}7$

X: Don't care

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	-0.5~4.6	V
DC input voltage	V_{IN}	-0.5~4.6	V
DC output voltage	V_{OUT}	-0.5~4.6 (Note1)	V
		-0.5~ $V_{CC} + 0.5$ (Note2)	
Input diode current	I_{IK}	-50	mA
Output diode current	I_{OK}	± 50 (Note3)	mA
DC output current	I_{OUT}	± 50	mA
Power dissipation	P_D	180	mW
DC V_{CC} / ground current	I_{CC}/I_{GND}	± 100	mA
Storage temperature	T_{stg}	-65~150	°C

Note1: $V_{CC} = 0$ V

Note2: High or low state. I_{OUT} absolute maximum rating must be observed.

Note3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	1.8~3.6	V
		1.2~3.6 (Note4)	
Input voltage	V_{IN}	-0.3~3.6	V
Output voltage	V_{OUT}	0~3.6 (Note5)	V
		0~ V_{CC} (Note6)	
Output current	I_{OH}/I_{OL}	± 24 (Note7)	mA
		± 18 (Note8)	
		± 6 (Note9)	
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~10 (Note10)	ns/V

Note4: Data retention only

Note5: $V_{CC} = 0$ V

Note6: High or low state

Note7: $V_{CC} = 3.0\sim 3.6$ VNote8: $V_{CC} = 2.3\sim 2.7$ VNote9: $V_{CC} = 1.8$ VNote10: $V_{IN} = 0.8\sim 2.0$ V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics ($T_a = -40\sim 85^\circ\text{C}$, $2.7\text{ V} < V_{CC} \leq 3.6\text{ V}$)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	“H” level	V _{IH}	—		2.7~3.6	2.0	—	V
	“L” level	V _{IL}	—		2.7~3.6	—	0.8	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	—	V
				I _{OH} = -12 mA	2.7	2.2	—	
				I _{OH} = -18 mA	3.0	2.4	—	
				I _{OH} = -24 mA	3.0	2.2	—	
	“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7~3.6	—	0.2	
				I _{OL} = 12 mA	2.7	—	0.4	
				I _{OL} = 18 mA	3.0	—	0.4	
				I _{OL} = 24 mA	3.0	—	0.55	
Input leakage current		I _{IN}	V _{IN} = 0~3.6 V	2.7~3.6	—	±5.0	μA	
Power OFF leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V	0	—	10.0	μA	
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND	2.7~3.6	—	20.0	μA	
			V _{CC} ≤ V _{IN} ≤ 3.6 V	2.7~3.6	—	±20.0		
Increase in I _{CC} per input		ΔI _{CC}	V _{IH} = V _{CC} - 0.6 V		2.7~3.6	—	750	

DC Characteristics ($T_a = -40 \sim 85^\circ\text{C}$, $2.3\text{ V} \leq V_{CC} \leq 2.7\text{ V}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
					V _{CC} (V)			
Input voltage	“H” level	V _{IH}	—		2.3~2.7	1.6	—	V
	“L” level	V _{IL}	—		2.3~2.7	—	0.7	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.3~2.7	V _{CC} - 0.2	—	V
				I _{OH} = -6 mA	2.3	2.0	—	
				I _{OH} = -12 mA	2.3	1.8	—	
				I _{OH} = -18 mA	2.3	1.7	—	
	“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.3~2.7	—	0.2	
				I _{OL} = 12 mA	2.3	—	0.4	
				I _{OL} = 18 mA	2.3	—	0.6	
Input leakage current		I _{IN}	V _{IN} = 0~3.6 V		2.3~2.7	—	±5.0	μA
Power OFF leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		2.3~2.7	—	20.0	μA
			V _{CC} ≤ V _{IN} ≤ 3.6 V		2.3~2.7	—	±20.0	

DC Characteristics ($T_a = -40 \sim 85^\circ\text{C}$, $1.8\text{ V} \leq V_{CC} < 2.3\text{ V}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
			V _{CC} (V)					
Input voltage	“H” level	V _{IH}	—		1.8~2.3	0.7 × V _{CC}	—	V
	“L” level	V _{IL}	—		1.8~2.3	—	0.2 × V _{CC}	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −100 μA	1.8	V _{CC} − 0.2	—	V
				I _{OH} = −6 mA	1.8	1.4	—	
	“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8	—	0.2	
				I _{OL} = 6 mA	1.8	—	0.3	
Input leakage current		I _{IIN}	V _{IN} = 0~3.6 V		1.8	—	±5.0	μA
Power OFF leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		1.8	—	20.0	μA
			V _{CC} ≤ V _{IN} ≤ 3.6 V		1.8	—	±20.0	

AC Characteristics (Ta = -40~85°C, Input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time (A, B, C- \bar{Y})	t_{pLH} t_{pHL}	(Fig. 1, 2)	1.8	1.0	8.2	ns
			2.5 \pm 0.2	0.8	4.1	
			3.3 \pm 0.3	0.6	3.5	
Propagation delay time (G1, \bar{Y})	t_{pLH} t_{pHL}	(Fig. 1, 2)	1.8	1.0	8.2	ns
			2.5 \pm 0.2	0.8	4.1	
			3.3 \pm 0.3	0.6	3.5	
Propagation delay time ($\bar{G2}$, \bar{Y})	t_{pLH} t_{pHL}	(Fig. 1, 2)	1.8	1.0	8.2	ns
			2.5 \pm 0.2	0.8	4.1	
			3.3 \pm 0.3	0.6	3.5	

For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Quiet output maximum dynamic V_{OL}	V_{OLP}	$V_{IH} = 1.8$ V, $V_{IL} = 0$ V (Note11)	1.8	0.25	V
		$V_{IH} = 2.5$ V, $V_{IL} = 0$ V (Note11)	2.5	0.6	
		$V_{IH} = 3.3$ V, $V_{IL} = 0$ V (Note11)	3.3	0.8	
Quiet output minimum dynamic V_{OL}	V_{OLV}	$V_{IH} = 1.8$ V, $V_{IL} = 0$ V (Note11)	1.8	-0.25	V
		$V_{IH} = 2.5$ V, $V_{IL} = 0$ V (Note11)	2.5	-0.6	
		$V_{IH} = 3.3$ V, $V_{IL} = 0$ V (Note11)	3.3	-0.8	
Quiet output minimum dynamic V_{OH}	V_{OHV}	$V_{IH} = 1.8$ V, $V_{IL} = 0$ V (Note11)	1.8	1.5	V
		$V_{IH} = 2.5$ V, $V_{IL} = 0$ V (Note11)	2.5	1.9	
		$V_{IH} = 3.3$ V, $V_{IL} = 0$ V (Note11)	3.3	2.2	

Note11: This parameter is guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Input capacitance	C_{IN}	—	1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C_{PD}	$f_{IN} = 10$ MHz (Note12)	1.8, 2.5, 3.3	40	pF

Note12: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Test Circuit

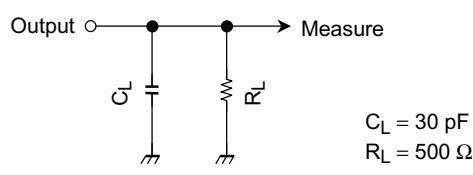
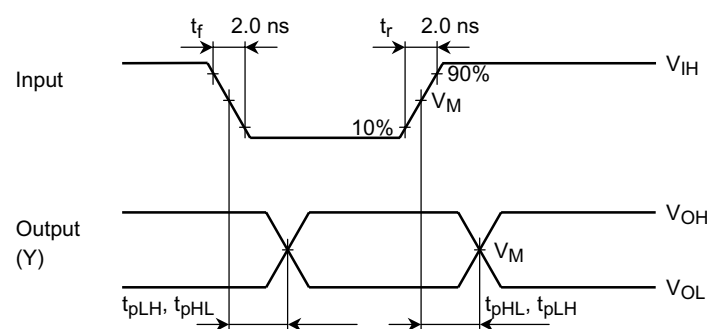


Figure 1

AC Waveform



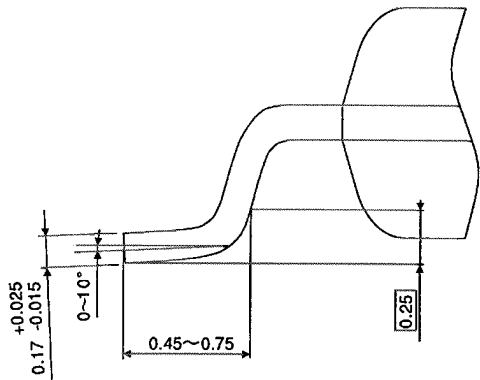
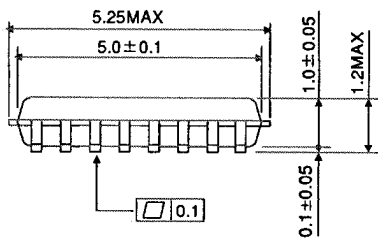
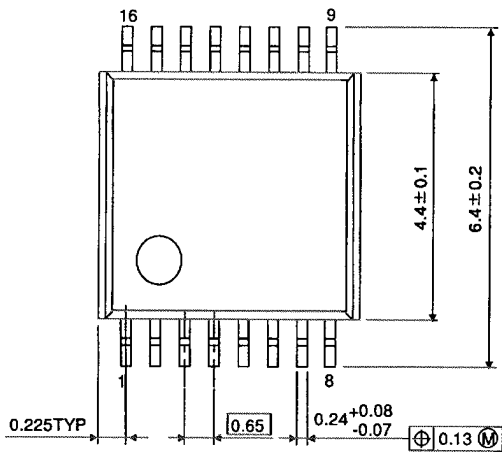
Symbol	V_{CC}		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	1.8 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_M	1.5 V	$V_{CC}/2$	$V_{CC}/2$

Figure 2 t_{pLH}, t_{pHL}

Package Dimensions

TSSOP16-P-0044-0.65

Unit : mm



Weight: 0.06 g (typ.)